2SC4500(L)/(S)

Silicon NPN Epitaxial

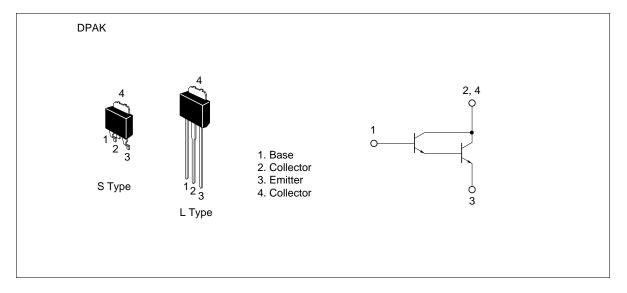
HITACHI

ADE-208-894 (Z) 1st. Edition Sep. 2000

Application

Low frequency amplifier

Outline





2SC4500(L)/(S)

Absolute Maximum Ratings (Ta = 25°C)

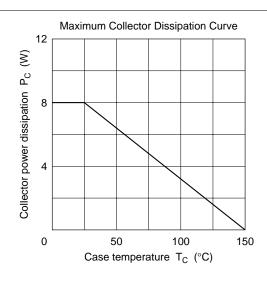
Item	Symbol	Ratings	Unit	
Collector to base voltage	V_{CBO}	60	V	
Collector to emitter voltage	V_{CEO}	60	V	
Emitter to base voltage	V_{EBO}	7	V	
Collector current	I _c	1	А	
Collector peak current	I _{C (peak)}	2	A	
Collector power dissipation	P _c	0.8	W	
	P _c *1	8		
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

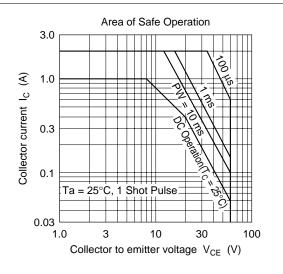
Note: 1. Value at $T_c = 25^{\circ}C$.

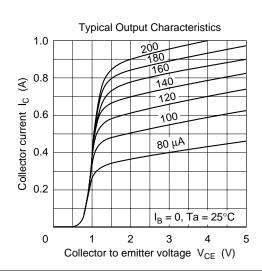
Electrical Characteristics (Ta = 25°C)

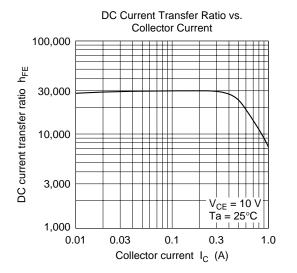
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	60	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	_	_	V	$I_E = 0.1 \text{ mA}, I_C = 0$
Collector cutoff current	I _{CBO}	_	_	10	μΑ	$V_{CB} = 60 \text{ V}, I_{E} = 0$
DC current transfer ratio	h _{FE}	2000	_	_		$V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}^{*1}$
Collector to emitter saturation voltage	V _{CE (sat)}	_	_	1.5	V	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}^{*1}$
Base to emitter saturation voltage	V _{BE (sat)}	_	_	2.0	V	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}^{*1}$
Turn on time	t _{on}	_	100	_	ns	$V_{CC} = 12 \text{ V, IC} = 250 \text{ mA},$
Turn off time	t _{off}	_	600	_	ns	$I_{B1} = -I_{B2} = 5 \text{ mA}$

Note: 1. Pulse Test.

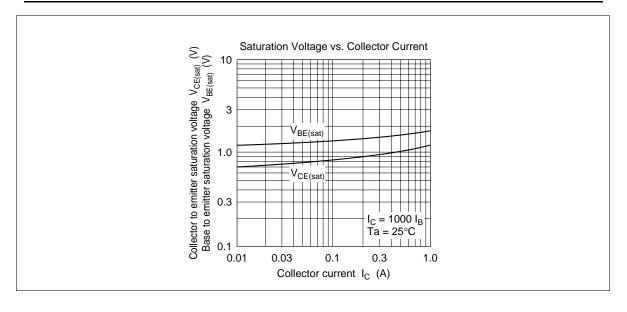




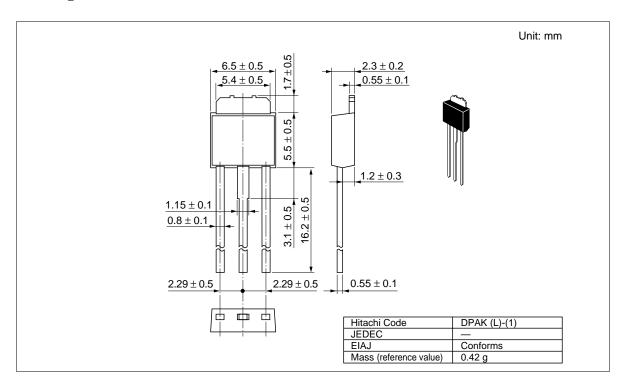


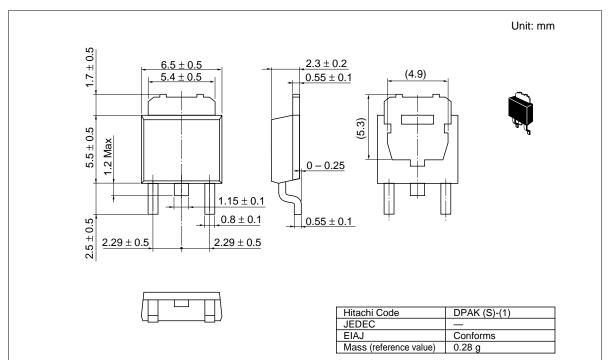


2SC4500(L)/(S)



Package Dimensions





HITACHI

Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

IITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica Europe Asia

Japan

http://semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg http://sicapac.hitachi-asia.com http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Germany Fax: <1>(408) 433-0223

Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585160

Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00, Singapore 049318 Tel: <65>-538-6533/538-8577 Fax: <65>-538-6933/538-3877 URL: http://www.hitachi.com.sg

Hitachi Asia I td (Taipei Branch Office)

4/F, No. 167, Tun Hwa North Road, Hung-Kuo Building. Taipei (105), Taiwan

Tel: <886>-(2)-2718-3666 Fax: <886>-(2)-2718-8180 Telex: 23222 HAS-TP URL: http://www.hitachi.com.tw 7/F., North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon, Hong Kong

Group III (Electronic Components)

Hitachi Asia (Hong Kong) Ltd.

Tel: <852>-(2)-735-9218 Fax: <852>-(2)-730-0281 URL: http://www.hitachi.com.hk

Copyright @ Hitachi, Ltd., 2000. All rights reserved. Printed in Japan. Colophon 2.0

HITACHI